

Wireless Bipolar Power Transistor 33W, 1930-1900 MHz

M/A-COM Products Released - Rev. 08.07

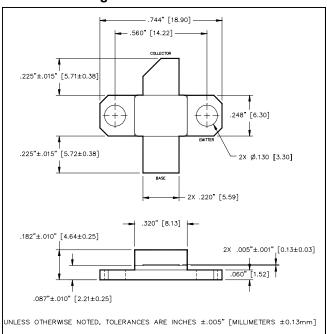
Features

- NPN silicon microwave power transistor
- Common emitter class AB operation
- · Internal input and output impedance matching
- · Diffused emitter ballasting
- Gold metallization system
- RoHS Compliant

ABSOLUTE MAXIMUM RATING AT 25°C

Parameter	Symbol	Rating	Units
Collector-Base Voltage	V_{CBO}	25	V
Collector-Emitter Voltage	V _{CES}	65	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current	Ic	4.7	Α
Power Dissipation	P _D	91	W
Junction Temperature	T_J	200	°C
Storage Temperature	T _{STG}	-55 to + 150	°C
Thermal Resistance	θ_{JC}	1.6	°C/W

Outline Drawing

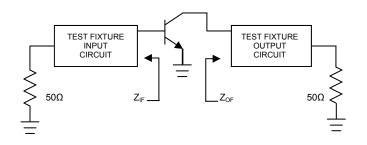


ELECTRICAL SPECIFICATIONS AT 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Power Gain	G_P	7.0	-	dB	V_{CC} = 25V, I_{CQ} = 200 mA, P_{out} = 33 W, F =1930, 1990 MHz
Collector Efficiency	ηC	40	-	%	V_{CC} = 25V, I_{CQ} = 200 mA, P_{out} = 33 W, F =1930, 1990 MHz
Input Return Loss	RL	10	-	dB	V _{CC} = 25V, I _{CQ} = 200 mA, P _{out} = 33 W, F =1930, 1990 MHz
Load Mismatch Tolerance	VSWR	-	2:1	-	V _{CC} = 25V, I _{CQ} = 200 mA, P _{out} = 33 W, F =1930, 1990 MHz

BROADBAND TEST FIXTURE IMPEDANCES

F (GHz)	Z _{IN} (Ω)	Z _{LOAD} (Ω)
1930	2.6 - j2.6	3.3 - j1.1
1960	2.5 - j2.5	3.8 - j1.0
1990	2.4 - j2.3	4.1 - j0.8



ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not quaranteed.

measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

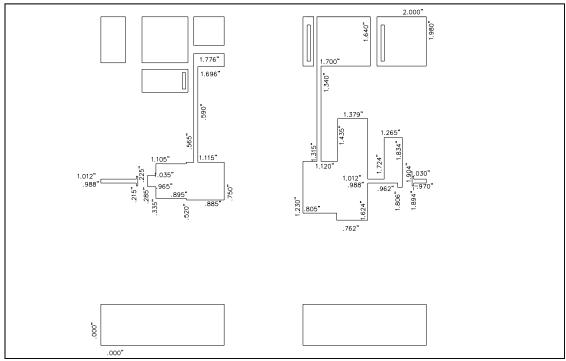
Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.



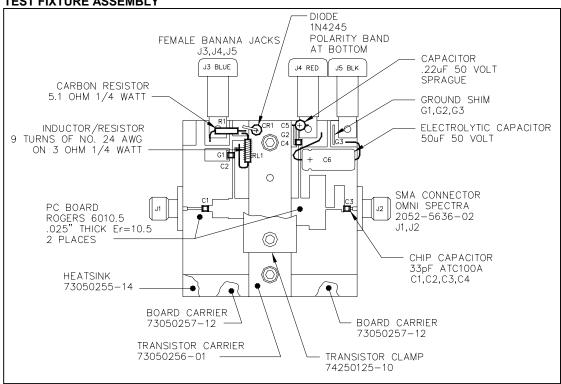
Wireless Bipolar Power Transistor 33W, 1930-1900 MHz

M/A-COM Products Released - Rev. 08.07

TEST FIXTURE DIMENSIONS



TEST FIXTURE ASSEMBLY



ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not quaranteed.

measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.